



Load Switch with Level-Shift

PRODUCT SUMMARY				
V _{DS2} (V)	$R_{DS(on)}(\Omega)$	I _D (A)		
1.8 to 8	0.060 at V _{IN} = 4.5 V	2.9		
	0.100 at V _{IN} = 2.5 V	2.2		
	0.175 at V _{IN} = 1.8 V	1.7		

DESCRIPTION

The Si3865BDV includes a p- and n-channel MOSFET in a single TSOP-6 package. The low on-resistance p-channel TrenchFET® is tailored for use as a load switch. The n-channel, with an external resistor, can be used as a levelshift to drive the p-channel load-switch. The n-channel MOSFET has internal ESD protection and can be driven by logic signals as low as 1.5 V. The Si3865BDV operates on supply lines from 1.8 V to 8 V, and can drive loads up to 2.9 A.

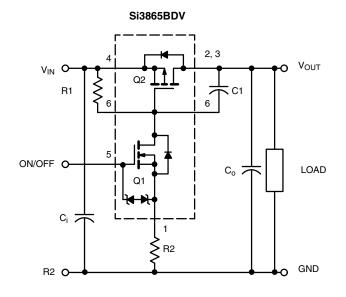
FEATURES

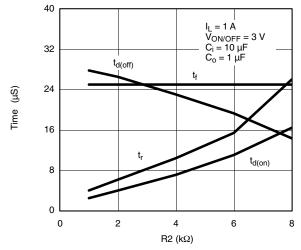
- Halogen-free According to IEC 61249-2-21 **Definition**
- 60 mΩ Low $R_{DS(on)}$ TrenchFET[®]: 1.8 V Rated
- 1.8 V to 8 V Input
- 1.5 V to 8 V Logic Level Control
- Low Profile, Small Footprint TSOP-6 Package
- 3000 V ESD Protection On Input Switch, VON/OFF
- Adjustable Slew-Rate
- Compliant to RoHS Directive 2002/95/EC

COMPLIANT **HALOGEN**

FREE

APPLICATION CIRCUITS





Note: For R2 switching variations with other V_{IN}/R1 combinations See Typical Characteristics

Switching Variation R2 at V_{IN} = 2.5 V, R1 = 20 k Ω

COMPONENTS				
R1	Pull-Up Resistor	Typical 10 k Ω to 1 M Ω^*		
R2	Optional Slew-Rate Control	Typical 0 to 100 kΩ*		
C1	Optional Slew-Rate Control	Typical 1000 pF		

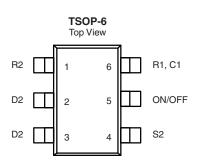
^{*} Minimum R1 value should be at least 10 x R2 to ensure Q1 turn-on.

The Si3865BDV is ideally suited for high-side load switching in portable applications. The integrated N-Channel level-shift device saves space by reducing external components. The slew rate is set externally so that rise-times can be tailored to different load types.

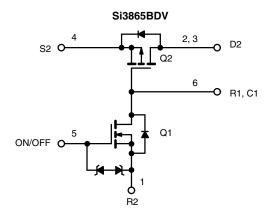
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FUNCTIONAL BLOCK DIAGRAM



Ordering Information: Si3865BDV-T1-E3 (Lead (Pb)-free) Si3865BDV-T1-GE3 (Lead (Pb)-free and Halogen-free)



ABSOLUTE MAXIMUM RATINGS (T	$A = 25 ^{\circ}C$, unles	ss otherwise no	ted)	
Parameter		Symbol	Limit	Unit
Input Voltage		V _{IN}	8	V
On/Off Voltage		V _{ON/OFF}	8	v
Load Current	Continuous ^{a, b}	I.	± 2.9	
Load Current	Pulsed ^{b, c}	'L	± 6	А
Continuous Intrinsic Diode Conduction ^a		I _S	- 1	
Maximum Power Dissipation ^a		P _D	0.83	W
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150	°C
ESD Rating, MIL-STD-883D Human Body Model (100 pF, 1500 Ω)		ESD	3	kV

THERMAL RESISTANCE RATINGS					
Parameter	Symbol	Typical	Maximum	Unit	
Maximum Junction-to-Ambient (continuous current) ^a	R _{thJA}	125	150	°C/W	
Maximum Junction-to-Foot (Q2)	R _{thJC}	40	55]	

SPECIFICATIONS (T _J = 25 °C, unless otherwise noted)								
Parameter	Symbol	Test Conditions			Тур.	Max.	Unit	
Off Characteristics								
Reverse Leakage Current	I _{FL}	V _{IN} = 8 V, V _{ON/OFF} = 0 V				1	μΑ	
Diode Forward Voltage	V_{SD}	I _S = - 1 A		- 0.77	- 1	V		
OnN Characteristics								
Input Voltage Range	V _{IN}		1.8		8	V		
	R _{DS(on)}	V _{ON/OFF} = 1.5 V, I _D = 1 A	V _{IN} = 4.5 V		0.045	0.060	Ω	
On-Resistance (P-Channel) at 1 A			V _{IN} = 2.5 V		0.075	0.100		
			V _{IN} = 1.8 V		0.135	0.175		
On-State (P-Channel) Drain-Current	I _{D(on)}	$V_{IN-OUT} \le 0.2 \text{ V}, V_{IN} = 5 \text{ V}, V_{ON/OFF} = 1.5 \text{ V}$		1			Α	
		$V_{IN-OUT} \le 0.3 \text{ V}, V_{IN} = 3 \text{ V}, V_{ON/OFF} = 1.5 \text{ V}$		1] ^	

Notes

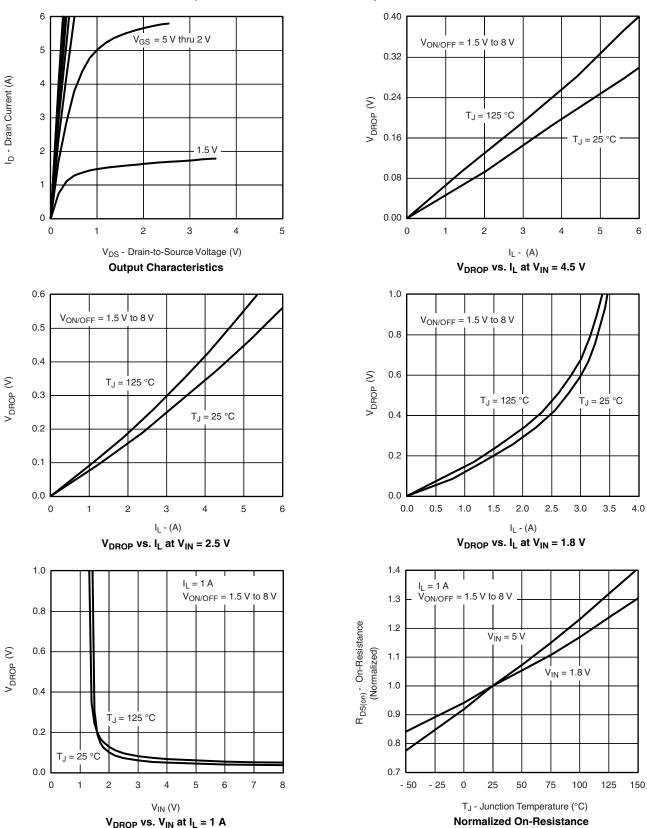
- a. Surface Mounted on FR4 board.
- b. $V_{IN} = 8$ V, $V_{ON/OFF} = 8$ V, $T_A = 25$ °C.
- c. Pulse test: pulse width $\leq 300~\mu s$, duty cycle $\leq 2~\%$.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.





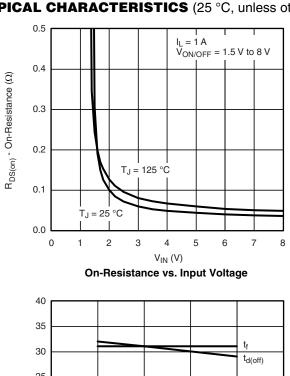
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

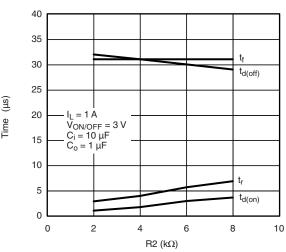


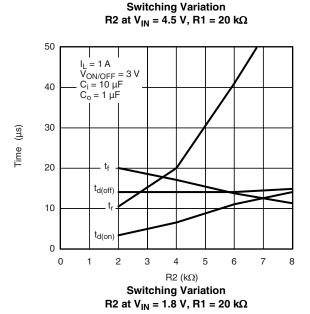
vs. Junction Temperature

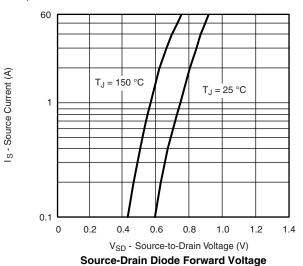
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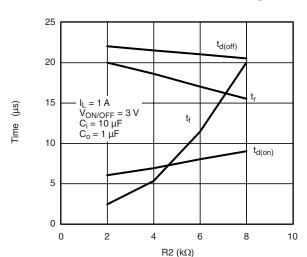
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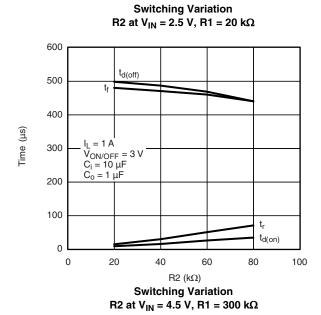








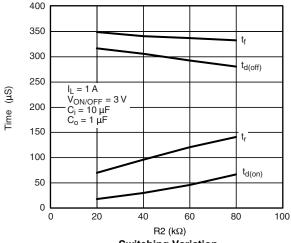








TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)

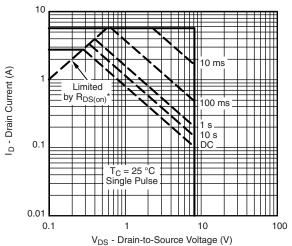


300 250 t_{d(off)} 200 $I_L = 1 A$ $V_{ON/OFF} = 3 V$ Time $C_i = 10 \, \mu F$ 150 $C_0 = 1 \mu F$ $t_{d(on)}$ 100 50 0 0 20 80 100 R2 ($k\Omega$)

350

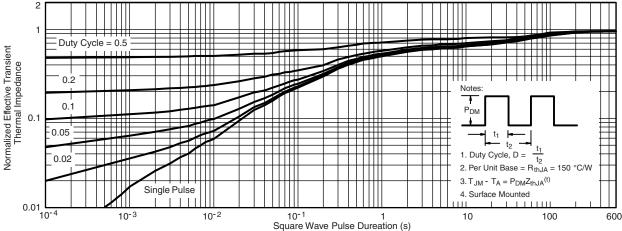
Switching Variation R2 at V_{IN} = 2.5 V, R1 = 300 k Ω

Switching Variation R2 at V_{IN} = 1.8 V, R1 = 300 k Ω



* V_{GS} > minimum V_{GS} at which $R_{DS(on)}$ is specified

Safe Operating Area, Junction-to-Case



Normalized Thermal Transient Impedance, Junction-to-Ambient

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